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| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|---|---------------|----------------------|---------------------|------------------|
| 10/777,469 | 02/11/2004 | Atsushi Itsuki | 09852/0200879-US0 | 2235 |
| 7278 75 | 90 06/14/2005 | | EXAMINER | |
| DARBY & DARBY P.C. | | | LUU, CHUONG A | |
| P. O. BOX 5257 NEW YORK, NY 10150-5257 | | | ART UNIT | PAPER NUMBER |
| • | | | 2818 | |

DATE MAILED: 06/14/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

| | | | _ |
|---|---|--|---|
| | Application No. | Applicant(s) | |
| | 10/777,469 | ITSUKI, ATSUSHI | |
| Office Action Summary | Examiner | Art Unit | _ |
| | Chuong A. Luu | 2818 | |
| The MAILING DATE of this communicat Period for Reply | ion appears on the cover sheet wi | th the correspondence address | |
| A SHORTENED STATUTORY PERIOD FOR THE MAILING DATE OF THIS COMMUNICA - Extensions of time may be available under the provisions of 37 after SIX (6) MONTHS from the mailing date of this communic - If the period for reply specified above is less than thirty (30) da - If NO period for reply is specified above, the maximum statuto - Failure to reply within the set or extended period for reply will, Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b). | TION. 'CFR 1.136(a). In no event, however, may a reation. ys, a reply within the statutory minimum of thirty period will apply and will expire SIX (6) MON by statute, cause the application to become AB | eply be timely filed y (30) days will be considered timely. THS from the mailing date of this communication. ANDONED (35 U.S.C. § 133). | |
| Status | | • | |
| 1) Responsive to communication(s) filed o | n | | |
| 2a) This action is FINAL . 2b) [| ☑ This action is non-final. | | |
| 3) Since this application is in condition for closed in accordance with the practice to | · · · · · · · · · · · · · · · · · · · | · • | |
| Disposition of Claims | | | |
| 4) ☐ Claim(s) 1-10 is/are pending in the appl 4a) Of the above claim(s) is/are v 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-10 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction | vithdrawn from consideration. | | |
| Application Papers | | | |
| 9) The specification is objected to by the Ex | kaminer. | | |
| 10) The drawing(s) filed on is/are: a) | \square accepted or b) \square objected to I | by the Examiner. | |
| Applicant may not request that any objection | - | , , | |
| Replacement drawing sheet(s) including the 11) The oath or declaration is objected to by | , | , , | |
| Priority under 35 U.S.C. § 119 | | | |
| a) Acknowledgment is made of a claim for the algorithms also also below also | numents have been received. Suments have been received in Apriority documents have been Bureau (PCT Rule 17.2(a)). | oplication No received in this National Stage | |
| Attachment(s) | | | |
| 1) ⊠ Notice of References Cited (PTO-892) 2) ☑ Notice of Draftsperson's Patent Drawing Review (PTO- | | ummary (PTO-413))/Mail Date | |
| 3) Information Disclosure Statement(s) (PTO-1449 or PTO Paper No(s)/Mail Date 3/17/2004. | | formal Patent Application (PTO-152) | |

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DETAILED ACTION

PRIOR ART REJECTIONS

Statutory Basis

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

The Rejections

Claims 1-7 are rejected under 35 U.S.C. 102(e) as being anticipated by Hanahata et al. (U.S. 6,787,191 B2).

Hanahata discloses an insulating thin film with

(1) the formula:
$$(R2)_2N$$
 $N(R2)_2$ $(R1) - Si-Si - (R1)$

wherein R₁ represents a hydrogen or methyl group, and R₂ represents an ethyl group, an propyl group or tertiary butyl group (see column 5, lines 2-60, column 6, lines 1-61);

(2) wherein the film forming method is one of a chemical vapor deposition method and a liquid phase epitaxy method (see column 28, lines 9-25);

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(3) wherein the chemical vapor deposition method a thermal chemical vapor deposition method;

- (4) wherein the Si-containing thin film formed is at least one selected from a SiaN4 thin film, a SiO2 thin film, and a Hf-O-Si thin film;
- (5) comprising steps of vaporizing the organic Si- containing compound, thermally decomposing the vaporized organic Si-containing compound and allowing the decomposed organic Si-containing compound to react with one of NH₃ gas and 0₂ gas (see column 26, lines 33-67, column 27, lines 1-32);
- (6) comprising steps of vaporizing the organic Si-containing compound and an organic hafnium compound, thermally decomposing the vaporized organic Si-containing compound and the vaporized organic hafnium compound, and allowing the decomposed compounds to react with 0₂ gas (see column 26, lines 33-67, column 27, lines 1-32);
- (7) wherein the formed Si-containing thin film does not contain CI (see column 5, lines 2-60, column 6, lines 1-61).

PRIOR ART REJECTIONS

Statutory Basis

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which

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said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

The Rejections

Claims 8-10 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hanahata et al. (U.S. 6,787,191 B2).

Hanahata teaches the outlined features above except for wherein forming the film is conducted at a temperature not greater than 700°C; wherein the film forming is performed in 5 minutes or less; wherein the thickness of the Sicontaining thin film is 50 nm or less. However, the operational parameters, such time and temperature and the thickness of the thin film are considered obvious. Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify wherein forming the film is conducted at a temperature not greater than 700°C; wherein the film forming is performed in 5 minutes or less; wherein the thickness of the Si-containing thin film is 50 nm or less of Hanahata's device within the range as claimed for the purpose of providing for reduced power consumption and increase operational speed, and it also has been held that where the general conditions of a claim are disclosed in the prior ad, discovering the optimum or workable ranges involves only routine skill in the art and it is noted that the applicant does not disclose criticality in the ranges claimed. In re Aller, 105 USPQ 233 (see MPEP j 2144.05).

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Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Chuong A. Luu whose telephone number is (571) 272-1902. The examiner can normally be reached on M-F (6:15-2:45).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David C. Nelms can be reached on (571) 272-1787. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Chuofig Anh Luu Patent Examiner June 8, 2005